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U.S. UTILITY Patent Application
O.I.P.E. PATEN

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PATENT DATE

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
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Takashi Ka Hiroki Oht Nobuhiko A	00	,		•	
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TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED		
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
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subsequent to (date) has been disclaimed.	(Assistant	Examiner) .	(Date)		· •	
The term of this patent shall not extend beyond the expiration date of U.S Patent. No.				ISS	UE FEE	
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Form PTO-436A			FILED WITH:	DISK (CRE)	JEICHE JOPBON	